N-Channel Power MOSFET 500 V, 1.5 Ω

Features

- Low ON Resistance
- Low Gate Charge
- ESD Diode-Protected Gate
- 100% Avalanche Tested
- 100% Rg Tested
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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V _{DSS}	R _{DS(on)} (MAX) @ 2.2 A
500 V	1.5 Ω

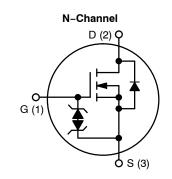
ABSOLUTE MAXIMUM RATINGS (T_C = 25° C unless otherwise noted)

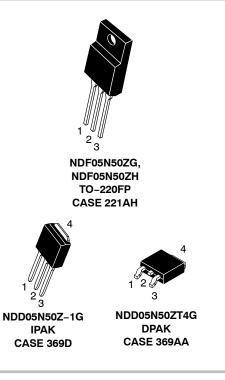
Rating	Symbol	NDF	NDD	Unit
Drain-to-Source Voltage	V _{DSS}	500		V
Continuous Drain Current $R_{\theta JC}$	۱ _D	5.5 (Note 1)	4.7	A
Continuous Drain Current $R_{\theta JC}$, $T_A = 100^{\circ}C$	۱ _D	3.5 (Note 1)	3	A
Pulsed Drain Current, V_{GS} @ 10 V	I _{DM}	20	19	А
Power Dissipation $R_{\theta JC}$	PD	30	83	W
Gate-to-Source Voltage	V _{GS}	±30		V
Single Pulse Avalanche Energy, $I_D = 5.0 A$	E _{AS}	130		mJ
ESD (HBM) (JESD22-A114)	V _{esd}	3000		V
RMS Isolation Voltage (t = 0.3 sec., R.H. \leq 30%, T _A = 25°C) (Figure 17)	V _{ISO}	4500		V
Peak Diode Recovery (Note 2)	dV/dt	4.5	-	V/ns
MOSFET dV/dt	dV/dt	60		V/ns
Continuous Source Current (Body Diode)	I _S	5		А
Maximum Temperature for Soldering Leads	ΤL	260		°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Limited by maximum junction temperature

2. $I_S = 4.4$ Å, di/dt ≤ 100 Å/µs, $V_{DD} \leq BV_{DSS}$, $T_J = +150^{\circ}C$





ORDERING AND MARKING INFORMATION

See detailed ordering, marking and shipping information on page 7 of this data sheet.

THERMAL RESISTANCE

Parameter			Value	Unit
Junction-to-Case (Drain)	NDF05N50Z NDD05N50Z	$R_{\theta JC}$	4.2 1.5	°C/W
Junction-to-Ambient Steady State	(Note 3) NDF05N50Z (Note 4) NDD05N50Z (Note 3) NDD05N50Z-1	$R_{ heta JA}$	50 38 80	

3. Insertion mounted

4. Surface mounted on FR4 board using 1" sq. pad size, (Cu area = 1.127 in sq [2 oz] including traces).

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Characteristic	Symbol	Test Conditions		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0 V, I _D = 1 mA		500			V
Breakdown Voltage Temperature Co- efficient	$\Delta BV_{DSS}/\Delta T_{J}$	Reference to 25°C, $I_D = 1 \text{ mA}$			0.6		V/°C
Drain-to-Source Leakage Current	I _{DSS}	<u>)// 500)//)/ 0)/</u>	25°C			1	μΑ
		V_{DS} = 500 V, V_{GS} = 0 V	150°C			50	
Gate-to-Source Forward Leakage	I _{GSS}	V _{GS} = ±20 V				±10	μΑ
ON CHARACTERISTICS (Note 5)							-
Static Drain-to-Source On-Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 2.2 /	Ą		1.25	1.5	Ω
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 50 \ \mu$	٩	3.0	3.9	4.5	V
Forward Transconductance	9FS	V _{DS} = 15 V, I _D = 2.5 A			3.5		S
OYNAMIC CHARACTERISTICS							-
Input Capacitance (Note 6)	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		421	530	632	pF
Output Capacitance (Note 6)	C _{oss}			50	68	80	
Reverse Transfer Capacitance (Note 6)	C _{rss}			8	15	25	
Total Gate Charge (Note 6)	Qg			9	18.5	28	nC
Gate-to-Source Charge (Note 6)	Q _{gs}			2	4	6	
Gate-to-Drain ("Miller") Charge (Note 6)	Q _{gd}	V _{DD} = 250 V, I _D = 5 A V _{GS} = 10 V	k,	5	10	15	
Plateau Voltage	V _{GP}				6.5		V
Gate Resistance	Rg			1.5	4.5	8	Ω
RESISTIVE SWITCHING CHARACTER	ISTICS				-		-
Turn-On Delay Time	t _{d(on)}				11		ns
Rise Time	t _r	V _{DD} = 250 V, I _D = 5 A	•,		15		1
Turn-Off Delay Time	t _{d(off)}	$V_{GS} = 10 \text{ V}, \text{ R}_{G} = 5 \Omega$	2		24	1	1
					1	+	4

SOURCE-DRAIN DIODE CHARACTERISTICS (T_C = $25^{\circ}C$ unless otherwise noted)

t_f

Diode Forward Voltage	V_{SD}	I _S = 5 A, V _{GS} = 0 V		1.6	V
Reverse Recovery Time	t _{rr}	$V_{GS} = 0 V, V_{DD} = 30 V$	255		ns
Reverse Recovery Charge	Q _{rr}	I _S = 5 A, di/dt = 100 A/μs	1.25		μC

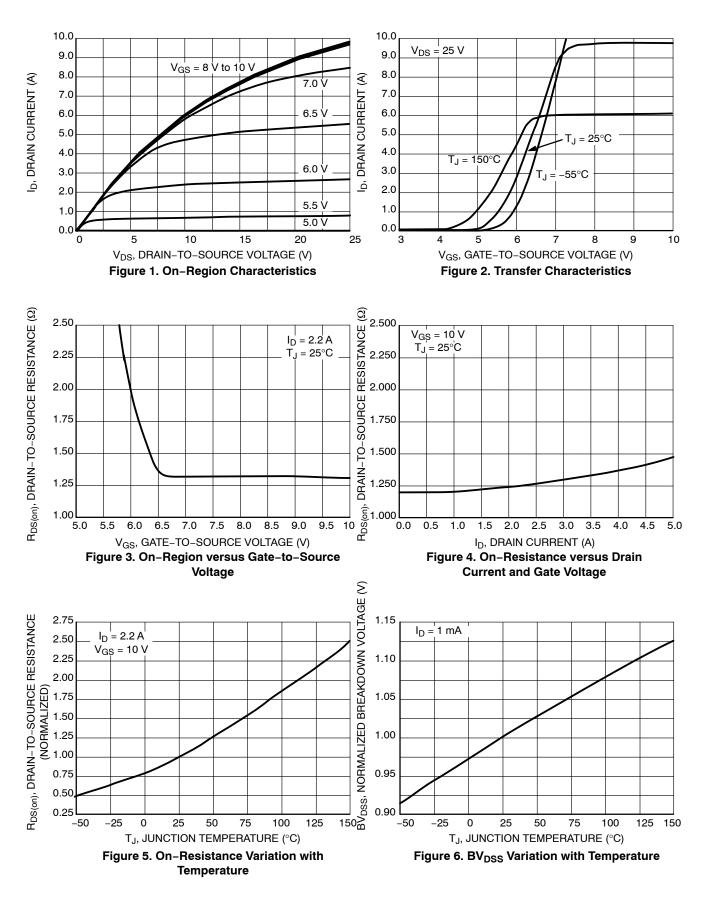
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

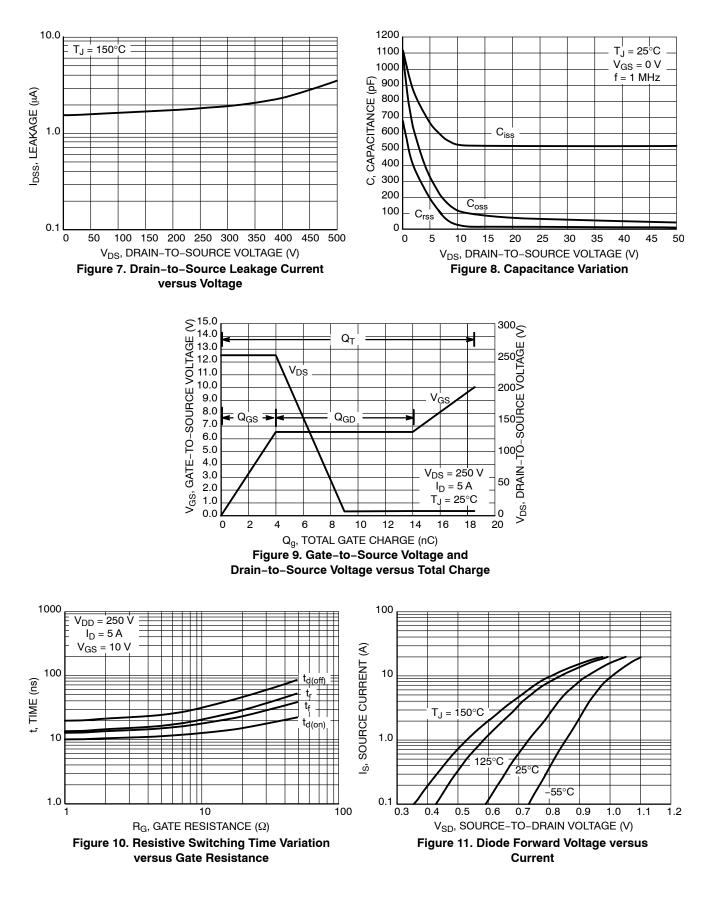
5. Pulse Width \leq 380 μ s, Duty Cycle \leq 2%. 6. Guaranteed by design.

Fall Time

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

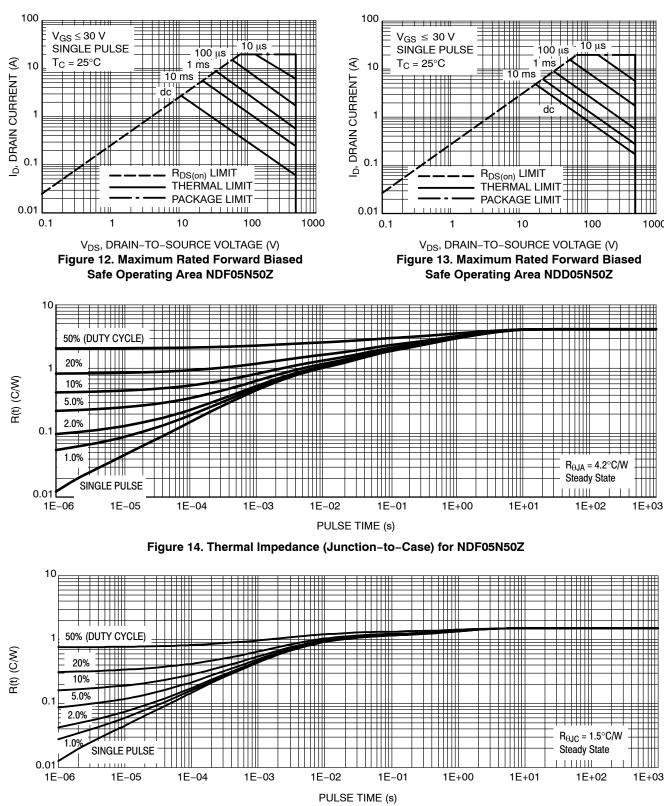
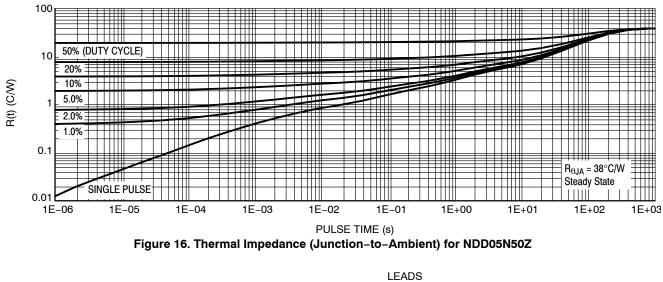


Figure 15. Thermal Impedance (Junction-to-Case) for NDD05N50Z

TYPICAL CHARACTERISTICS



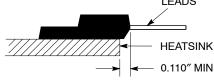


Figure 17. Isolation Test Diagram

Measurement made between leads and heatsink with all leads shorted together.

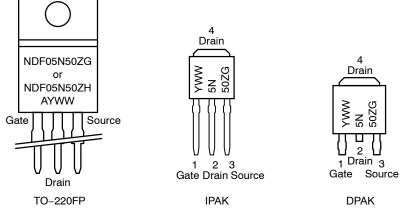
*For additional mounting information, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

Order Number	Package	Shipping [†]
NDF05N50ZG	TO-220FP (Pb-Free, Halogen-Free)	50 Units / Rail
NDF05N50ZH	TO-220FP (Pb-Free, Halogen-Free)	50 Units / Rail
NDD05N50Z-1G	IPAK (Pb-Free, Halogen-Free)	75 Units / Rail
NDD05N50ZT4G	DPAK (Pb-Free, Halogen-Free)	2500 / Tape and Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS



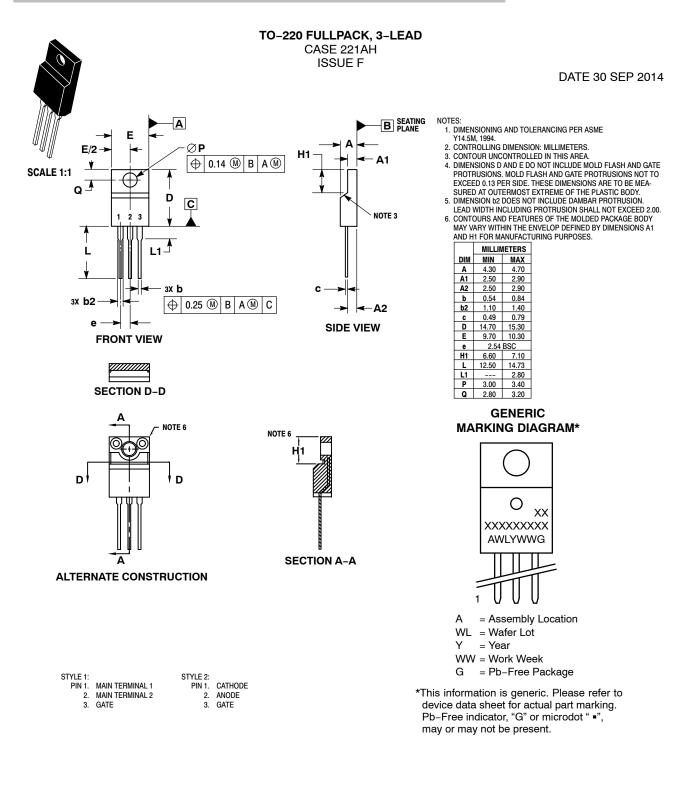
A = Location Code

Υ

WW = Work Week

G, H = Pb-Free, Halogen-Free Package

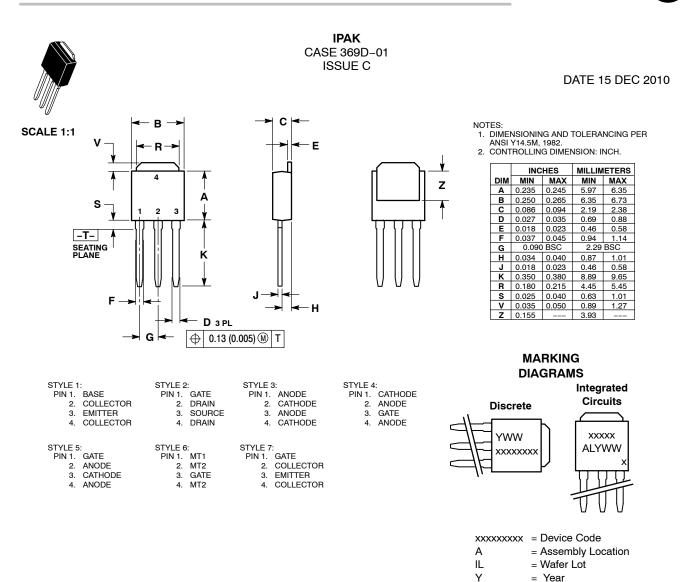




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WW

= Work Week

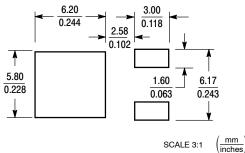
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L4



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 03 JUN 2010

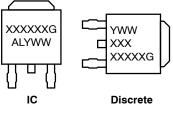
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- 2. CONTROLLING DIMENSION: INCHES. 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- THERMAL FAD CONTOR OF FIGURE WITHIN DEMONSIONS b3, L3 and Z.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL
- NOT EXCEED 0.006 INCHES PER SIDE 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
Е	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29	BSC
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108	REF	2.74	REF
L2	0.020	0.020 BSC 0.51 BS0		BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Ζ	0.155		3.93	

MARKING DIAGRAM*



= Device Code = Assembly Location L = Wafer Lot Y = Year = Work Week WW G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

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